

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Applicant:	§	
Alessia Pavan et al.	§	Art Unit: 2894
	§	
Serial No.: 10/749,130	§	
	§	Examiner: Amar Movva
Filed: December 30, 2003	§	
	§	
For: Non-Volatile Memory Cell	§	Conf No.: 3296
Comprising Dielectric Layers	§	
Having a Low Dielectric	§	
Constant and Corresponding	§	Docket: NUM.0104US
Manufacturing Process	§	02-AG-317

Mail Stop **AF**
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

REPLY TO FINAL REJECTION

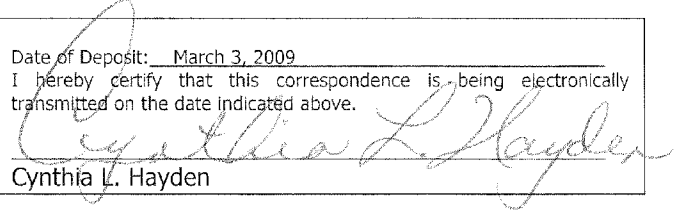
Sir:

In response to the office action mailed January 15, 2009, reconsideration is requested in view of the following remarks.

A current listing of the claims is attached. No amendments were made to the claims.

Date of Deposit: March 3, 2009

I hereby certify that this correspondence is being electronically transmitted on the date indicated above.


Cynthia L. Hayden